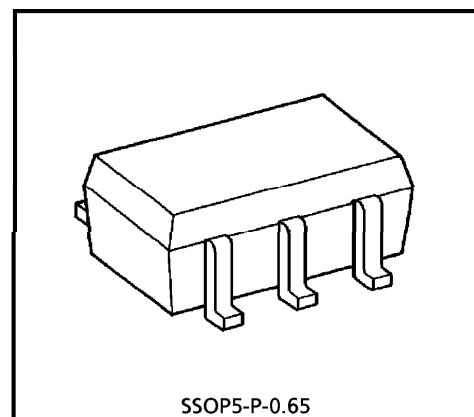


TA4012FU

UHF WIDE BAND AMPLIFIER APPLICATIONS

FEATURES

- Low Current : $I_{CC} = 6.5\text{mA}$
- Wide Band : $f = 2.0\text{GHz}$ (3dB down)
- Operating Supply Voltage : $V_{CC} = 1.5\sim 3\text{V}$



SSOP5-P-0.65

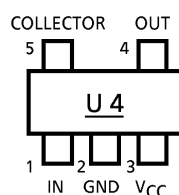
Weight : 0.006g (Typ.)

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	4	V
Total Power Dissipation	P_D (Note 1)	300	mW
Operating Temperature	T_{opr}	$-40\sim 85$	$^\circ\text{C}$
Storage Temperature	T_{stg}	$-55\sim 150$	$^\circ\text{C}$

(Note 1) When mounted on the glass epoxy of $2.5\text{cm}^2 \times 1.6\text{t}$

PIN ASSIGNMENT



CAUTION

This device electrostatic sensitivity. Please handle with caution.

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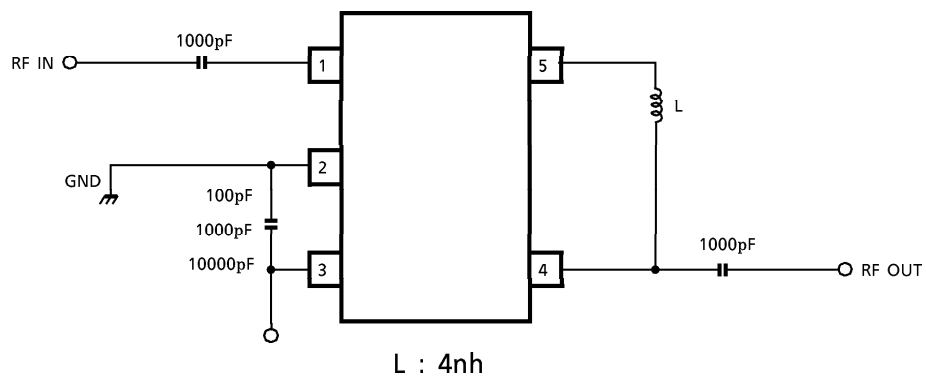
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ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$, $Z_g = Z_l = 50\Omega$)

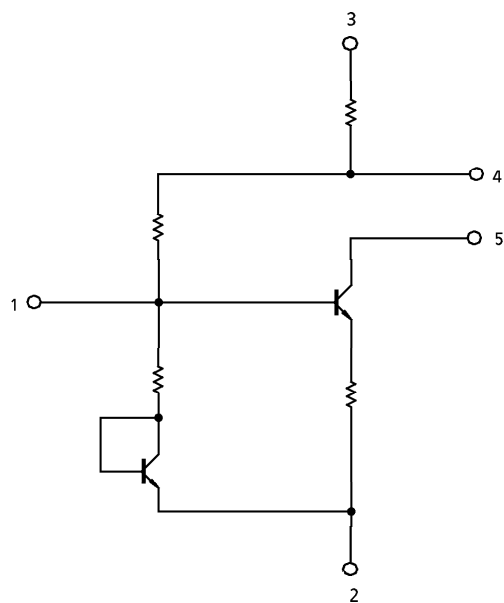
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Circuit Current	I_{CC}	$V_{CC} = 2\text{V}$, Non carrier	4.5	6.5	8.5	mA
Band Width	BW	$V_{CC} = 2\text{V}$ (Note 2)	1.8	2.0	—	GHz
Insertion Gain	$ S_{21} ^2$	$V_{CC} = 2\text{V}$, $f = 1.5\text{GHz}$	10	12	—	dB
Noise Figure	NF	$V_{CC} = 2\text{V}$, $f = 1.5\text{GHz}$	—	6	7.5	dB
Isolation	$ S_{12} ^2$	$V_{CC} = 2\text{V}$, $f = 1.5\text{GHz}$	—	-22	—	dB
Input Return Loss	$ S_{11} ^2$	$V_{CC} = 2\text{V}$, $f = 1.5\text{GHz}$	—	-6.5	—	dB
Output Return Loss	$ S_{22} ^2$	$V_{CC} = 2\text{V}$, $f = 1.5\text{GHz}$	—	-7.5	—	dB
Output Power at 1dB Gain Compression	Po1dB	$V_{CC} = 2\text{V}$, $f = 1.5\text{GHz}$	—	0	—	dBmW

(Note 2) BW is the frequency of 3dB down from $|S_{21}|^2$ at 1.5GHz.

RF TEST CIRCUIT (TOP VIEW)

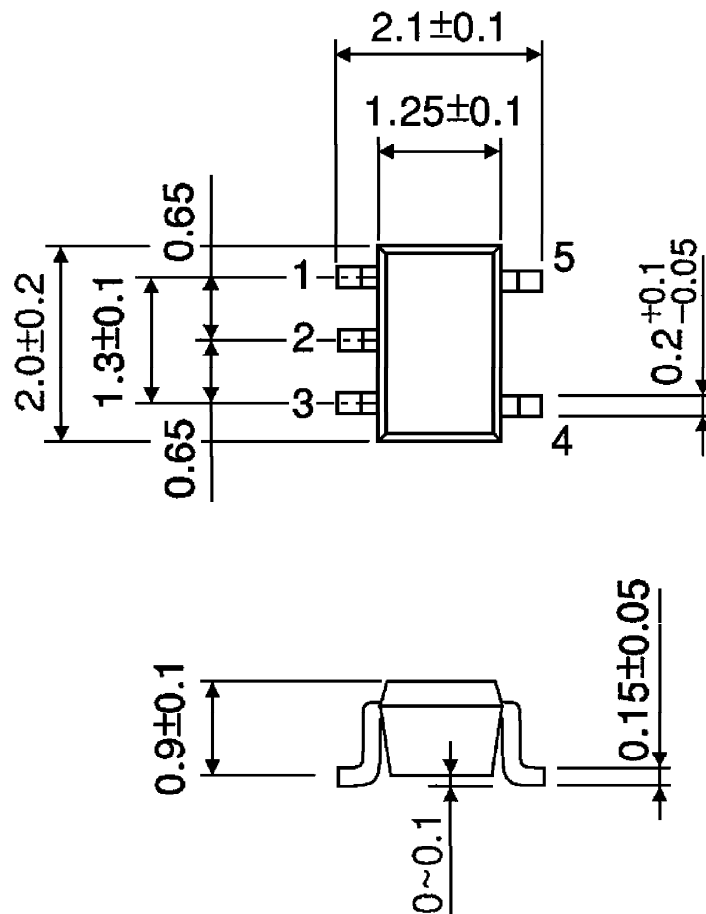


EQUIVALENT CIRCUIT



OUTLINE DRAWING
SSOP5-P-0.65

Unit : mm



Weight : 0.006g (Typ.)